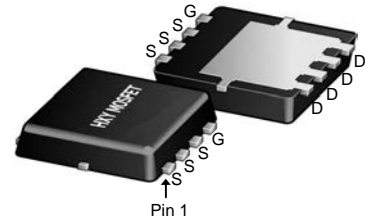




General Description

The DMTH10H010LPS-13 use advanced SGT MOSFET technology to provide low RDS(ON), low gate charge, fast switching and excellent avalanche characteristics. This device is specially designed to get better ruggedness.

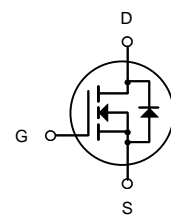


DFN5X6-8L
(Power(5x6))

General Features

$V_{DS} = 100V$ $I_D = 75A$

$R_{DS(ON)} < 7.5m\Omega @ V_{GS}=10V$



N-Channel MOSFET

Applications

Consumer electronic power supply Motor control
Synchronous-rectification Isolated DC
Synchronous-rectification applications

Package Marking and Ordering Information

| Product ID | Pack | Brand | Qty(PCS) |
|------------------|-----------------------|------------|----------|
| DMTH10H010LPS-13 | DFN5X6-8L(Power(5x6)) | HXY MOSFET | 5000 |

Absolute Maximum Ratings at $T_j=25^{\circ}C$ unless otherwise noted

| Parameter | Symbol | Value | Unit |
|--|-----------|------------|---------------|
| Drain source voltage | VDS | 100 | V |
| Gate source voltage | VGS | ± 20 | V |
| Continuous drain current ¹⁾ | ID | 75 | A |
| Pulsed drain current ²⁾ | ID, pulse | 300 | A |
| Power dissipation ³⁾ | PD | 97 | W |
| Single pulsed avalanche energy ⁵⁾ | EAS | 90 | mJ |
| Operation and storage temperature | Tstg, Tj | -55 to 150 | $^{\circ}C$ |
| Thermal resistance, junction-case | RθJC | 1.3 | $^{\circ}C/W$ |



Electrical Characteristics (T_J=25°C unless otherwise specified)

| Symbol | Parameter | Test Condition | Min. | Typ. | Max. | Units |
|--|---|--|------|------|------|-------|
| Off Characteristic | | | | | | |
| V _{(BR)DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V, I _D =250μA | 100 | - | - | V |
| I _{DSS} | Zero Gate Voltage Drain Current | V _{DS} =100V, V _{GS} =0V, | - | - | 1.0 | μA |
| I _{GSS} | Gate to Body Leakage Current | V _{DS} =0V, V _{GS} = ±20V | - | - | ±100 | nA |
| On Characteristics | | | | | | |
| V _{GS(th)} | Gate Threshold Voltage | V _{DS} =V _{GS} , I _D =250μA | 1.0 | 1.6 | 2.5 | V |
| R _{DS(on)} | Static Drain-Source on-Resistance <small>note3</small> | V _{GS} =10V, I _D =20A | - | 6.4 | 7.5 | mΩ |
| | | V _{GS} =4.5V, I _D =8A | - | 9.2 | 11.4 | mΩ |
| Dynamic Characteristics | | | | | | |
| C _{iss} | Input Capacitance | V _{DS} =50V, V _{GS} =0V, f=1.0MHz | - | 2944 | - | pF |
| C _{Oss} | Output Capacitance | | - | 736 | - | pF |
| C _{rss} | Reverse Transfer Capacitance | | - | 2.04 | - | pF |
| Q _g | Total Gate Charge | V _{DS} =50V, I _D =30A, V _{GS} =10V | - | 39.4 | - | nc |
| Q _{gs} | Gate-Source Charge | | - | 5.6 | - | nc |
| Q _{gd} | Gate-Drain(“Miller”) Charge | | - | 7.6 | - | nc |
| Switching Characteristics | | | | | | |
| t _{d(on)} | Turn-on Delay Time | V _{DD} =50V, I _D =25A, R _G =6Ω, V _{GS} =10V | - | 13 | - | nc |
| t _r | Turn-on Rise Time | | - | 27.5 | - | nc |
| t _{d(off)} | Turn-off Delay Time | | - | 45.5 | - | nc |
| t _f | Turn-off Fall Time | | - | 41.5 | - | nc |
| Drain-Source Diode Characteristics and Maximum Ratings | | | | | | |
| I _S | Maximum Continuous Drain to Source Diode Forward Current | | - | - | 75 | A |
| I _{SM} | Maximum Pulsed Drain to Source Diode Forward Current | | - | - | 300 | A |
| V _{SD} | Drain to Source Diode Forward Voltage | V _{GS} =0V, I _S =30A | - | - | 1 | V |
| t _{rr} | Body Diode Reverse Recovery Time | T _J =25°C, I _F =12A,dI/dt=100A/μs | - | 177 | - | ns |
| Q _{rr} | Body Diode Reverse Recovery Charge | | - | 1291 | - | nc |

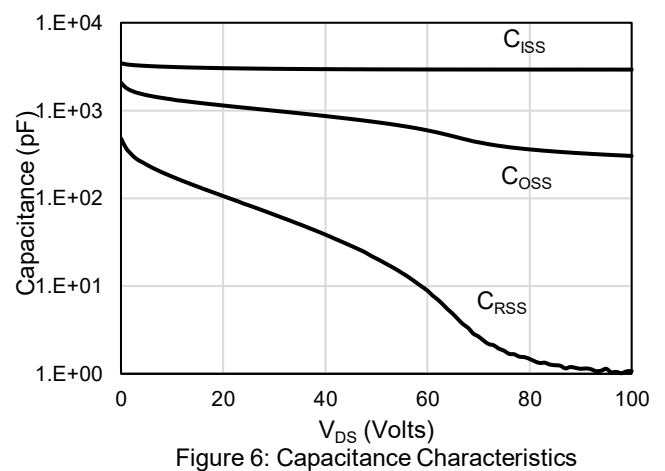
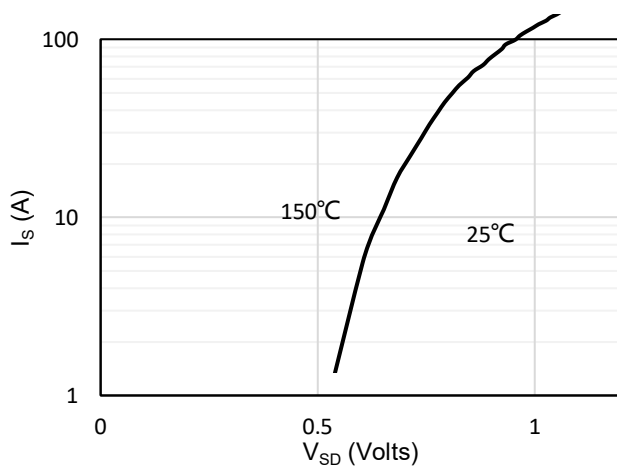
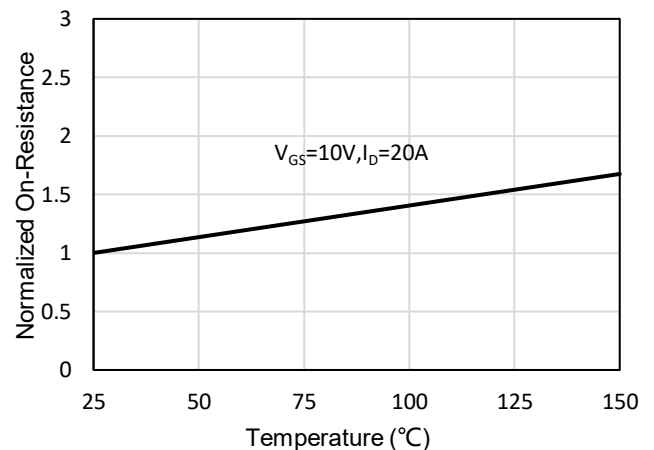
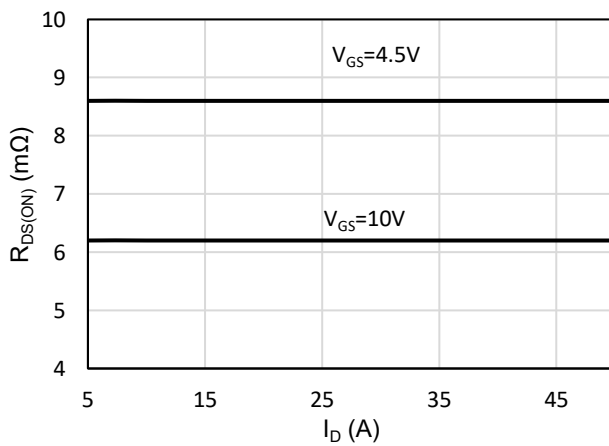
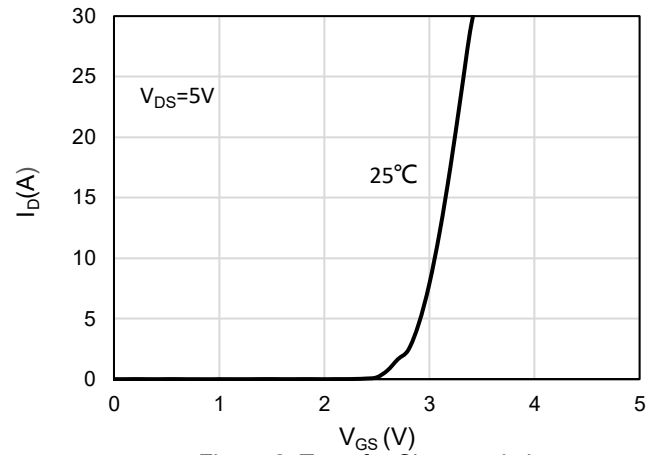
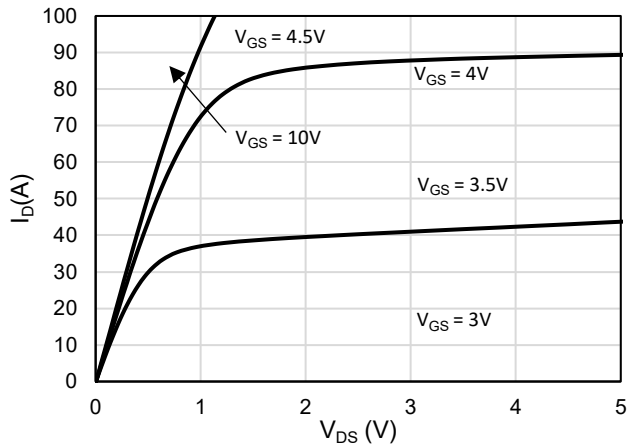
Notes:1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature

2. EAS condition: T_J=25°C, V_{DD}=50V, V_G=10V, R_G=25Ω, L=0.5mH, I_{AS}=19A

3. Pulse Test: Pulse Width≤300μs, Duty Cycle≤0.5%



Typical Performance Characteristics



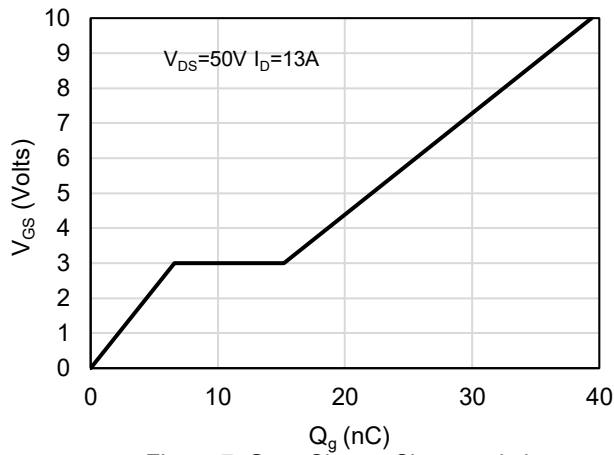


Figure 7: Gate-Charge Characteristics

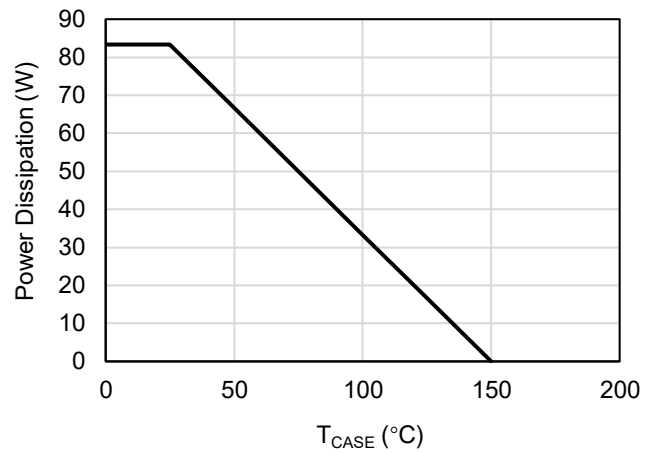


Figure 8: Power De-rating

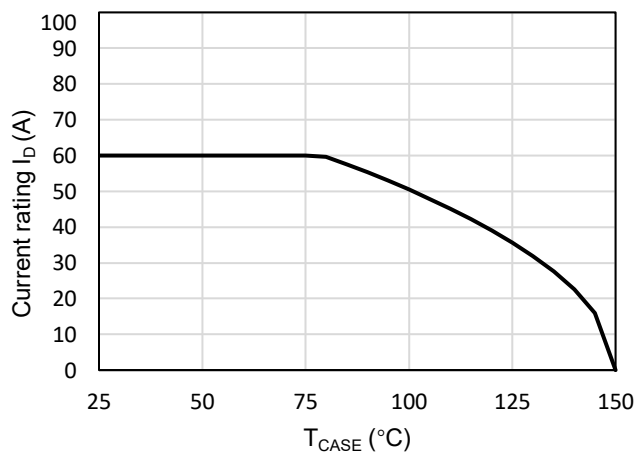


Figure 9: Current De-rating

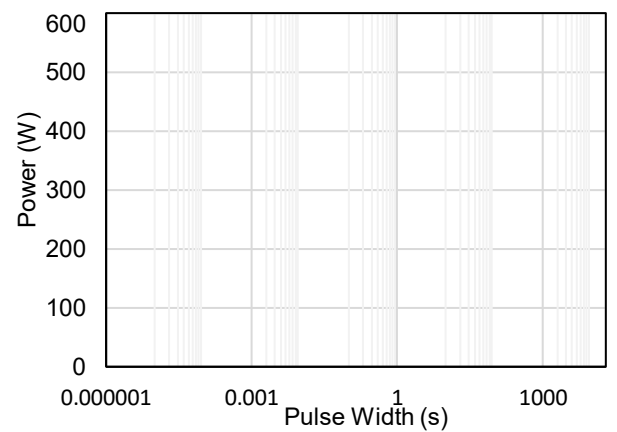


Figure 10: Single Pulse Power Rating Junction-to-Case

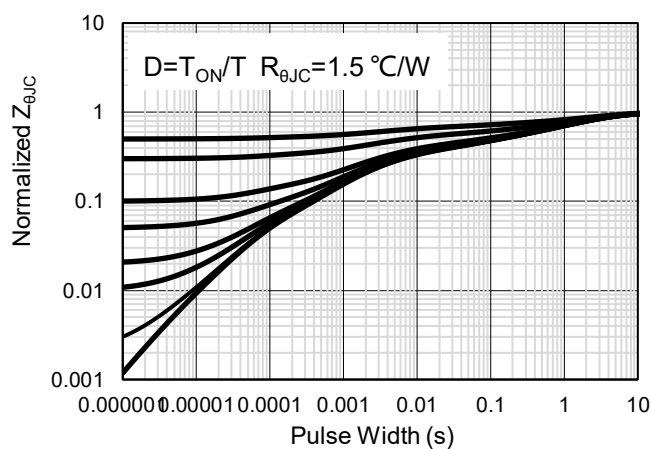


Figure 11: Normalized Maximum Transient Thermal Impedance

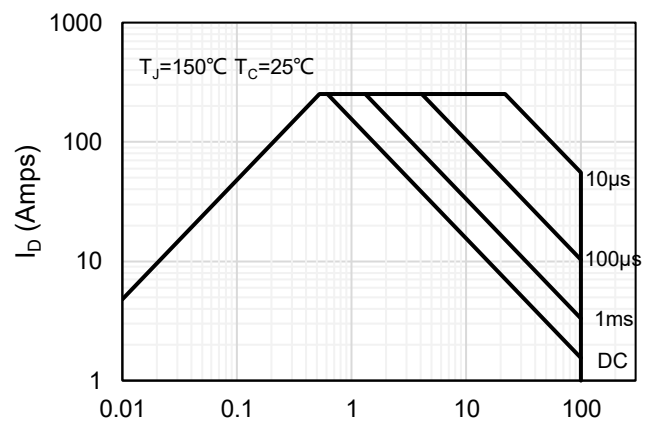
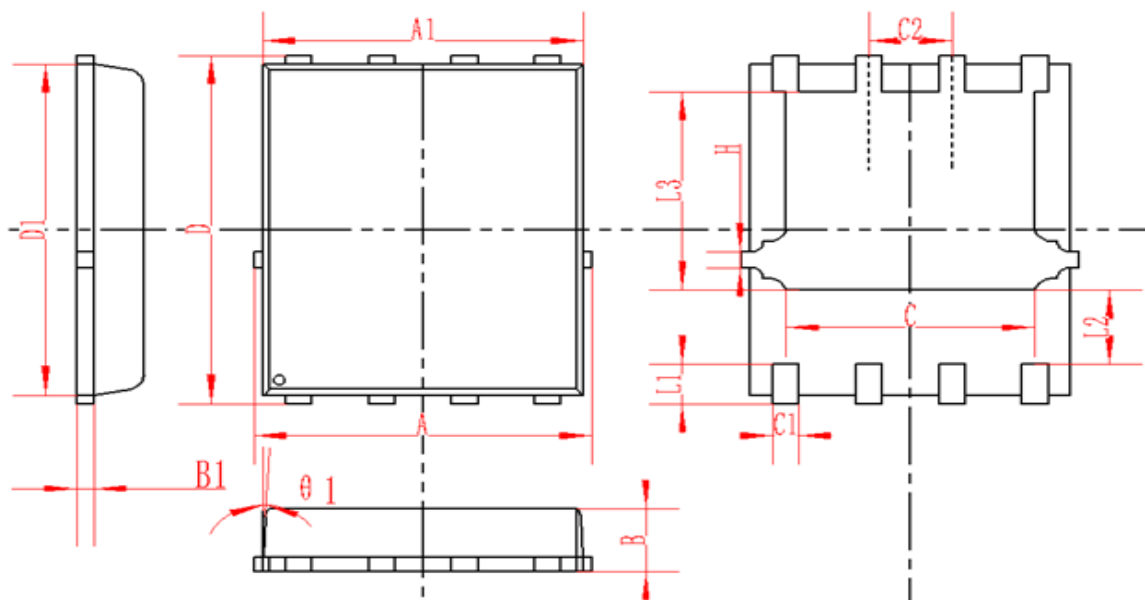


Figure 12: Maximum Forward Biased Safe Operating Area



DFN5X6-8L(Power(5x6)) Package Information



| SYMBOL | MM | | | INCH | | |
|--------|----------|------|-------|----------|-------|-------|
| | MIN | NOM | MAX | MIN | NOM | MAX |
| A | 4.95 | 5 | 5.05 | 0.195 | 0.197 | 0.199 |
| A1 | 4.82 | 4.9 | 4.98 | 0.190 | 0.193 | 0.196 |
| D | 5.98 | 6 | 6.02 | 0.235 | 0.236 | 0.237 |
| D1 | 5.67 | 5.75 | 5.83 | 0.223 | 0.226 | 0.230 |
| B | 0.9 | 0.95 | 1 | 0.035 | 0.037 | 0.039 |
| B1 | 0.254REF | | | 0.010REF | | |
| C | 3.95 | 4 | 4.05 | 0.156 | 0.157 | 0.159 |
| C1 | 0.35 | 0.4 | 0.45 | 0.014 | 0.016 | 0.018 |
| C2 | 1.27TYP | | | 0.5TYP | | |
| θ1 | 8° | 10° | 12° | 8° | 10° | 12° |
| L1 | 0.63 | 0.64 | 0.65 | 0.025 | 0.025 | 0.026 |
| L2 | 1.2 | 1.3 | 1.4 | 0.047 | 0.051 | 0.055 |
| L3 | 3.415 | 3.42 | 3.425 | 0.134 | 0.135 | 0.135 |
| H | 0.24 | 0.25 | 0.26 | 0.009 | 0.010 | 0.010 |



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